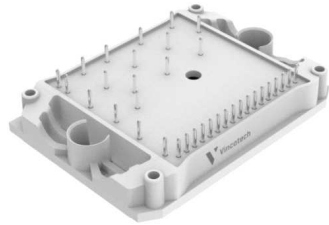
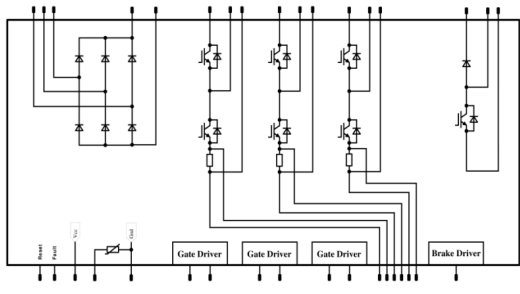




| flow IPM 1C | | 1200 V / 15 A |
|--|--|---|
| Features <ul style="list-style-type: none"> • Three-phase input rectifier • Three-phase inverter with emitter shunts • Gate drives with bootstrap circuit • Brake chopper with gate drive • Overcurrent protection • Undervoltage lockout • Temperature sensor | | flow 1C 12 mm housing  |
| Target applications <ul style="list-style-type: none"> • Embedded Drives • Industrial Drives | | Schematic  |
| Types <ul style="list-style-type: none"> • 20-1C12IBA015SH-LB18A08 | | |

Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|--|------------|---|-------|------------------|
| Rectifier Diode | | | | |
| Peak Repetitive Reverse Voltage | V_{RRM} | | 1600 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 24 | A |
| Surge (non-repetitive) forward current | I_{FSM} | 50 Hz Single Half Sine Wave $t_p = 10\text{ ms}$ $T_j = 150\text{ °C}$ | 230 | A |
| Surge current capability | I^2t | | 260 | A ² s |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 27 | W |
| Maximum Junction Temperature | T_{jmax} | | 150 | °C |



Vincotech

Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-----------------------------------|------------|---------------------------------------|-------|---------|
| Inverter Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 1200 | V |
| Collector current | I_C | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 13 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 45 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 29 | W |
| Short circuit ratings | t_{SC} | $T_j \leq 150\text{ °C}$ | 10 | μs |
| | V_{CC} | $V_{GE} = 15\text{ V}$ | 800 | V |
| Maximum junction temperature | T_{jmax} | | 175 | °C |

| | | | | |
|-------------------------------------|------------|---------------------------------------|------|----|
| Inverter Diode | | | | |
| Peak Repetitive Reverse Voltage | V_{RRM} | | 1200 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 11 | A |
| Repetitive peak forward current | I_{FRM} | | 30 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 16 | W |
| Maximum Junction Temperature | T_{jmax} | | 150 | °C |

| | | | | |
|-----------------------------|-----------|---------------------------------|-----------------------|---|
| Gate Driver Inverter | | | | |
| Supply voltage | V_{CC} | | -0,5...+24 | V |
| Logic input voltage | V_{in} | UH, UL, VH, VL, WH, WL, FO, RST | -0,5... V_{cc} +0,5 | V |
| Internal current limit | I_{MAX} | | 16,7 | A |

| | | | | |
|-----------------------|-----------|----------------------|---|---|
| Inverter Shunt | | | | |
| Max DC current | I_{MAX} | $T_c = 25\text{ °C}$ | 9 | A |

| | | | | |
|-----------------------------------|------------|---------------------------------------|------|---------|
| Brake Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 1200 | V |
| Collector current | I_C | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 13 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 45 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 29 | W |
| Short circuit ratings | t_{SC} | $T_j \leq 150\text{ °C}$ | 10 | μs |
| | V_{CC} | $V_{GE} = 15\text{ V}$ | 800 | V |
| Maximum junction temperature | T_{jmax} | | 175 | °C |



Vincotech

Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-------------------------------------|------------|---------------------------------------|-------|------|
| Brake Diode | | | | |
| Peak Repetitive Reverse Voltage | V_{RRM} | | 1200 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 6 | A |
| Repetitive peak forward current | I_{FRM} | | 15 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 12 | W |
| Maximum Junction Temperature | T_{jmax} | | 150 | °C |

Brake Sw. Protection Diode

| | | | | |
|-------------------------------------|------------|---------------------------------------|------|----|
| Peak Repetitive Reverse Voltage | V_{RRM} | | 1200 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 4 | A |
| Repetitive peak forward current | I_{FRM} | | 6 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 8 | W |
| Maximum Junction Temperature | T_{jmax} | | 150 | °C |

Gate Driver Brake

| | | | | |
|----------------------|------------|--|---------------------------|----|
| Supply voltage | V_{CC} | | 7 | V |
| Logic input voltage | V_{in} | | $-0,3 \dots V_{cc} + 0,3$ | V |
| Junction Temperature | T_{jmax} | | 150 | °C |

Module Properties

Thermal Properties

| | | | | |
|---|-----------|--|-----------------------------|----|
| Storage temperature | T_{stg} | | $-40 \dots +125$ | °C |
| Operation temperature under switching condition | T_{jop} | | $-40 \dots (T_{jmax} - 25)$ | °C |

Isolation Properties

| | | | | |
|----------------------------|------------|-------------------------------------|-----------|----|
| Isolation voltage | V_{isol} | DC Test Voltage* $t_p = 2\text{ s}$ | 6000 | V |
| | | AC Voltage $t_p = 1\text{ min}$ | 2500 | V |
| Creepage distance | | | min. 12,7 | mm |
| Clearance | | | 7,18 | mm |
| Comparative Tracking Index | CTI | | > 200 | |

*100 % tested in production



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Rectifier Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|------|----|-----------|--|--------------|------------|----|
| Forward voltage | V_F | | | | 30 | 25 125 | | 1,25 1,24 | 1,29 | V |
| Reverse leakage current | I_r | | | 1600 | | 25 150 | | | 10 1000 | μA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material $\lambda = 3,4$ W/mK | | | | | | 2,60 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Inverter Switch

Static

| | | | | | | | | | | |
|--------------------------------------|--------------|-------------------|----|------|--------|-----------|------|--------------|------|----|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{GE} = V_{CE}$ | | | 0,0005 | 25 | 5,3 | 5,8 | 6,3 | V |
| Collector-emitter saturation voltage | V_{CEsat} | | 15 | | 15 | 25 150 | 1,78 | 1,89 2,28 | 2,42 | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 1200 | | 25 | | | 2 | μA |
| Internal gate resistance | r_g | | | | | | | none | | Ω |
| Input capacitance | C_{ies} | $f = 1$ MHz | 0 | 25 | 25 | | | 875 | | pF |
| Output capacitance | C_{oes} | | | | | | | 75 | | |
| Reverse transfer capacitance | C_{res} | | | | | | | 45 | | |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material $\lambda = 3,4$ W/mK | | | | | | 3,26 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|--|-----------------------------------|-----|---|-----------|--|----------------|--|-----|
| Turn-on delay time* | $t_{d(on)}$ | $Q_{iFWD} = 1,3$ μC $Q_{tFWD} = 2,5$ μC | $V_{CC} = 15$ V $V_{IN} = 5$ V | 600 | 9 | 25 125 | | 1507 1938 | | ns |
| Rise time | t_r | | | | | 25 125 | | 17 19 | | |
| Turn-off delay time* | $t_{d(off)}$ | | | | | 25 125 | | 1507 2012 | | |
| Fall time | t_f | | | | | 25 125 | | 25 88 | | |
| Turn-on energy (per pulse) | E_{on} | $Q_{iFWD} = 1,3$ μC $Q_{tFWD} = 2,5$ μC | $V_{CC} = 15$ V $V_{IN} = 5$ V | 600 | 9 | 25 125 | | 0,559 0,816 | | mWs |
| Turn-off energy (per pulse) | E_{off} | | | | | 25 125 | | 0,395 0,730 | | |

* times include gate driver propagation delay



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Inverter Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|------|----|-----------|--|--------------|-----|----|
| Forward voltage | V_F | | | | 15 | 25 125 | | 1,76 1,73 | | V |
| Reverse leakage current | I_r | | | 1200 | | 25 | | | 250 | μA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material $\lambda = 3,4$ W/mK | | | | | | 4,37 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|--|-----------------------------------|-----|---|-----------|--|----------------|--|------|
| Peak recovery current | I_{RRM} | $di/dt = 595$ A/μs $di/dt = 536$ A/μs | $V_{CC} = 15$ V $V_{IN} = 5$ V | 600 | 9 | 25 125 | | 9 12 | | A |
| Reverse recovery time | t_{rr} | | | | | 25 125 | | 285 464 | | ns |
| Recovered charge | Q_r | | | | | 25 125 | | 1,272 2,489 | | μC |
| Reverse recovered energy | E_{rec} | | | | | 25 125 | | 0,477 0,988 | | mWs |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 25 125 | | 38 40 | | A/μs |



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Gate Driver Inverter

Static

| | | | | | | | | | | |
|---|--------------------|---|--|--|--|--|------|------|------|----|
| Recommended supply voltage | V_{CC} | | | | | | 13,5 | 15 | 20 | V |
| Power on reset trip voltage | V_{POR} | | | | | | 4,0 | 5,5 | 7,5 | V |
| Internal current limit | I_{MAX} | | | | | | 13,3 | 16,7 | 20 | A |
| Quiescent supply current | I_q | | | | | | | 3 | 4,5 | mA |
| Logic "1" input voltage | V_{IH} | UH, UL, VH, VL, WH, WL, RST | | | | | 2,2 | 3 | 4 | V |
| Logic "0" input voltage | V_{IL} | | | | | | 0,6 | 1,5 | 2,1 | V |
| Logic "1" input current | I_{inH} | $V_{in} = 5$ V | | | | | 0,6 | 1 | 1,4 | mA |
| Logic "0" input current | I_{inL} | $V_{in} = 0$ V | | | | | 0 | 0 | 0,01 | mA |
| Input signal filter time | t_{Filt} | UH, UL, VH, VL, WH, WL, FO (in), RST (pulse) | | | | | 80 | 200 | 500 | ns |
| Logic "1" FAULT output* | $V_{outFAULTH}$ | $I_{FAULT} = 1$ mA | | | | | | | 0,95 | V |
| Logic "1" FAULT input treshold voltage* | $V_{inFAULTH}$ | | | | | | 0,6 | 1,5 | 2,1 | V |
| Logic "0" FAULT input treshold voltage* | $V_{inFAULTL}$ | | | | | | 2,2 | 3 | 4 | V |
| Under voltage reset voltage | $V_{UVreset}$ | | | | | | 10 | 10,8 | 11,6 | V |
| Under voltage trip voltage | V_{UVtrip} | | | | | | 10,5 | 11,3 | 12,1 | V |
| Under voltage hysteresis voltage | $V_{UVhysteresis}$ | | | | | | 0,2 | 0,5 | 0,8 | V |

Inverter Shunt

Static

| | | | | | | | | | | |
|------------|-----|--|--|--|--|--|--|----|--|----|
| Resistance | R | | | | | | | 30 | | mΩ |
|------------|-----|--|--|--|--|--|--|----|--|----|



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Brake Switch

Static

| | | | | | | | | | | |
|--------------------------------------|--------------|---------------------|----|------|--------|-----------|------|--------------|------|----|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{CE} = V_{CE}$ | | | 0,0005 | 25 | 5,3 | 5,8 | 6,3 | V |
| Collector-emitter saturation voltage | V_{CEsat} | | 15 | | 15 | 25 150 | 1,78 | 1,89 2,28 | 2,42 | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 1200 | | 25 | | | 2 | µA |
| Internal gate resistance | r_g | | | | | | | none | | Ω |
| Input capacitance | C_{ies} | $f = 1 \text{ MHz}$ | 0 | 25 | | 25 | | 875 | | pF |
| Output capacitance | C_{oes} | | | | | | | 75 | | |
| Reverse transfer capacitance | C_{res} | | | | | | | 45 | | |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material $\lambda = 3,4 \text{ W/mK}$ | | | | | | 3,26 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|--|---|-----|----|-----------|--|----------------|--|-----|
| Turn-on delay time* | $t_{d(on)}$ | | $V_{IN} = 5 \text{ V}$ $V_{CC} = 15 \text{ V}$ | 600 | 10 | 25 125 | | 44 49 | | ns |
| Rise time | t_r | | | | | 25 125 | | 17 20 | | |
| Turn-off delay time* | $t_{d(off)}$ | | | | | 25 125 | | 299 369 | | |
| Fall time | t_f | | | | | 25 125 | | 16 43 | | |
| Turn-on energy (per pulse) | E_{on} | $Q_{iFWD} = 1 \text{ µC}$ $Q_{rFWD} = 1,8 \text{ µC}$ | | | | 25 125 | | 0,579 0,771 | | mWs |
| Turn-off energy (per pulse) | E_{off} | | | | | 25 125 | | 0,339 0,598 | | |

* times include gate driver deadtime



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Brake Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|------|-----|------------------|--|----------------------|-----|----|
| Forward voltage | V_F | | | | 7,5 | 25 125 150 | | 2,00 1,99 1,99 | | V |
| Reverse leakage current | I_r | | | 1200 | | 25 | | | 250 | μA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material $\lambda = 3,4$ W/mK | | | | | | 5,86 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|--|-----------------------------------|-----|----|-----------|--|----------------|--|------|
| Peak recovery current | I_{RRM} | $di/dt = 588$ A/μs $di/dt = 560$ A/μs | $V_{IN} = 5$ V $V_{CC} = 15$ V | 600 | 10 | 25 125 | | 8 9 | | A |
| Reverse recovery time | t_{rr} | | | | | 25 125 | | 327 494 | | ns |
| Recovered charge | Q_r | | | | | 25 125 | | 1,008 1,759 | | μC |
| Reverse recovered energy | E_{rec} | | | | | 25 125 | | 0,416 0,754 | | mWs |
| Peak rate of fall of recovery current | $(di_{rr}/dt)_{max}$ | | | | | 25 125 | | 31 40 | | A/μs |

Brake Sw. Protection Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|------|---|-----------|--|--------------|-----|----|
| Forward voltage | V_F | | | | 3 | 25 150 | | 1,65 1,51 | 2,3 | V |
| Reverse leakage current | I_r | | | 1200 | | 25 | | | 250 | μA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material $\lambda = 3,4$ W/mK | | | | | | 9,21 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Gate Driver Brake

Static

| | | | | | | | | | | |
|-----------------------------------|-----------|----------------|--|--|--|--|------|-----|-----|------------|
| Recommended supply voltage | V_{DD} | | | | | | 4,5 | 6 | 7 | V |
| Turn-On Voltage | V_{ON} | | | | | | 3,5 | 3,9 | 4,3 | V |
| Turn-Off Voltage | V_{OFF} | | | | | | 3,3 | 3,7 | 4,1 | V |
| Logic "1" input threshold voltage | V_{inH} | | | | | | 30 | | | % V_{DD} |
| Logic "0" input threshold voltage | V_{inL} | | | | | | | | 70 | % V_{DD} |
| Logic "1" input current | I_{inH} | $V_{in} = 5$ V | | | | | -1 | | 175 | μA |
| Logic "0" input current | I_{inL} | $V_{in} = 0$ V | | | | | -175 | | 1 | μA |
| Logic Hysteresis Voltage | V_{HYS} | | | | | | | 17 | | % V_{DD} |

Thermistor

| | | | | | | | | | | |
|----------------------------|----------------|--------------------|--|--|--|-----|-----|------|-----|------|
| Rated resistance | R | | | | | 25 | | 22 | | kΩ |
| Deviation of R_{100} | $\Delta_{R/R}$ | $R_{100} = 1486$ Ω | | | | 100 | -12 | | +14 | % |
| Power dissipation | P | | | | | 25 | | 200 | | mW |
| Power dissipation constant | | | | | | 25 | | 2 | | mW/K |
| B-value | $B_{(25/50)}$ | Tol. ±3% | | | | 25 | | 3950 | | K |
| B-value | $B_{(25/100)}$ | Tol. ±3% | | | | 25 | | 3998 | | K |
| Vincotech NTC Reference | | | | | | | | | B | |



Vincotech

Rectifier Diode Characteristics

figure 1. Rectifier Diode
Typical forward characteristics

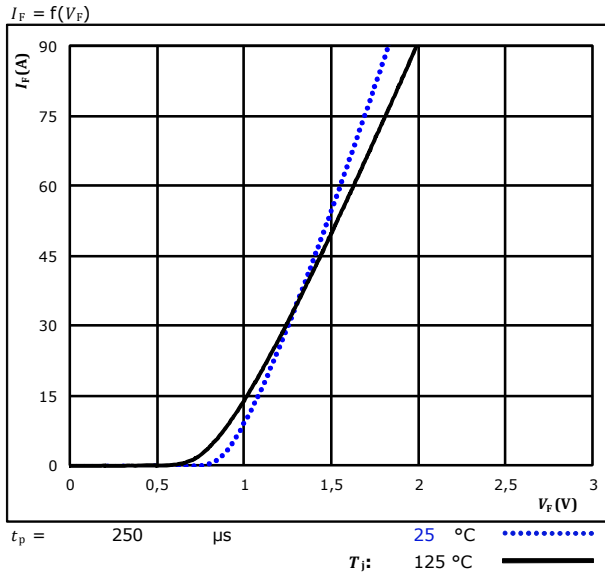
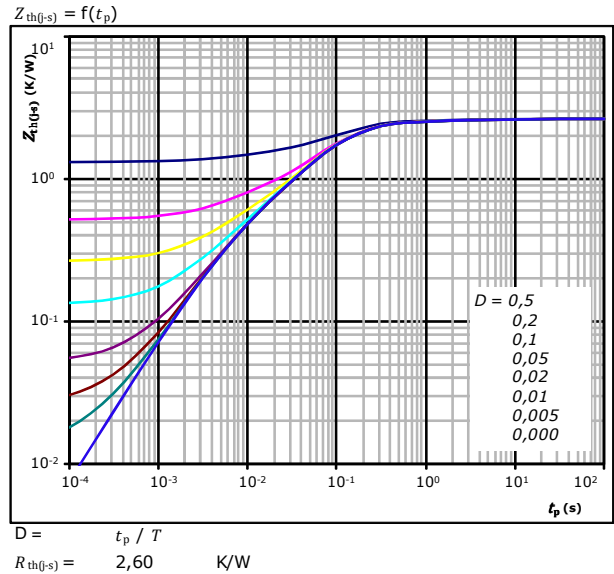


figure 2. Rectifier Diode
Transient thermal impedance as a function of pulse width



Diode thermal model values

| R (K/W) | τ (s) |
|-----------|------------|
| 6,39E-02 | 7,39E+00 |
| 1,82E-01 | 8,47E-01 |
| 1,37E+00 | 1,17E-01 |
| 7,19E-01 | 4,63E-02 |
| 2,48E-01 | 5,84E-03 |
| 2,07E-02 | 5,09E-03 |



Vincotech

20-1C12IBA015SH-LB18A08 datasheet

Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics

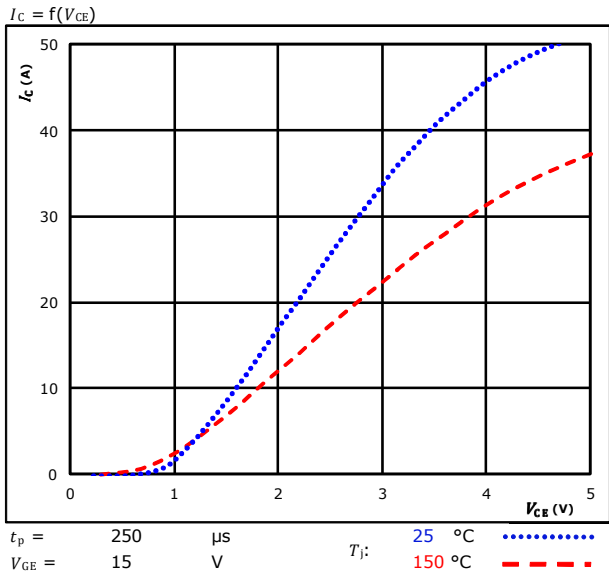


figure 2. IGBT

Typical output characteristics

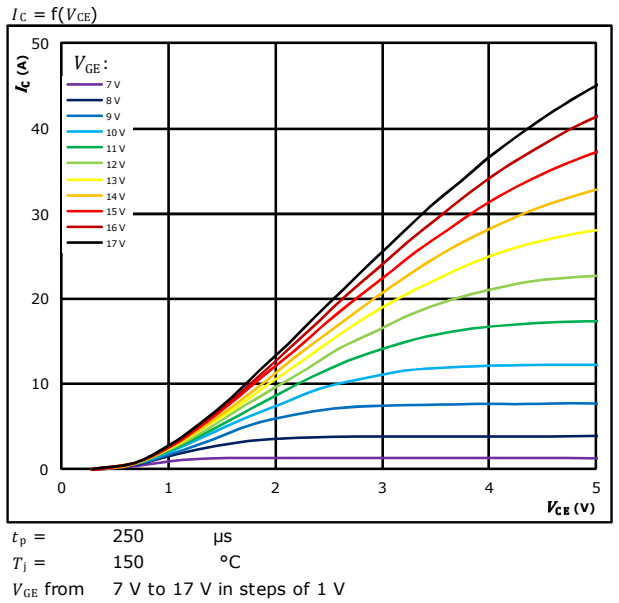


figure 3. IGBT

Typical transfer characteristics

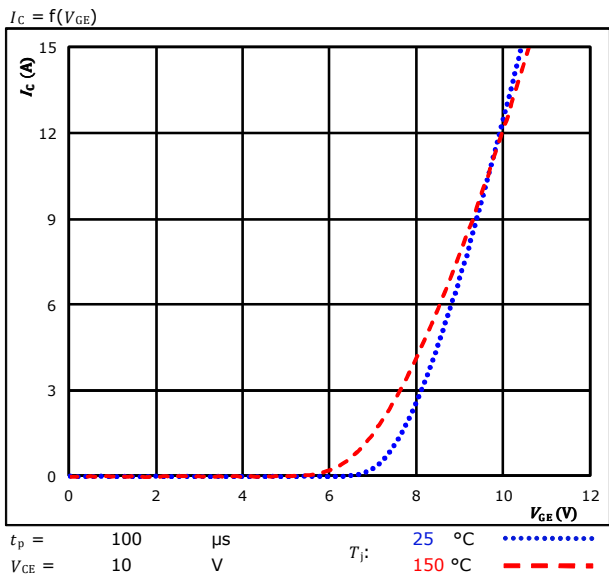
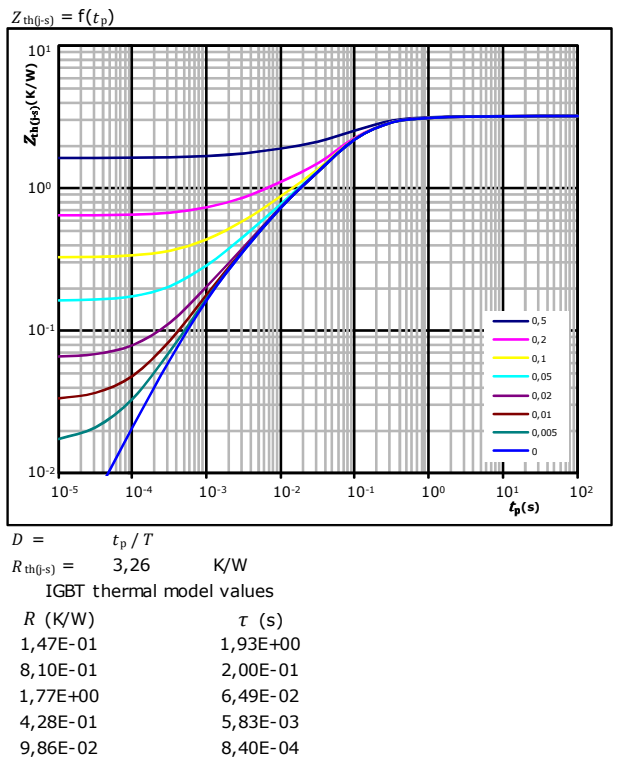


figure 4. IGBT

Transient thermal impedance as function of pulse duration





Vincotech

Inverter Switch Characteristics

figure 5. IGBT

Gate voltage vs gate charge

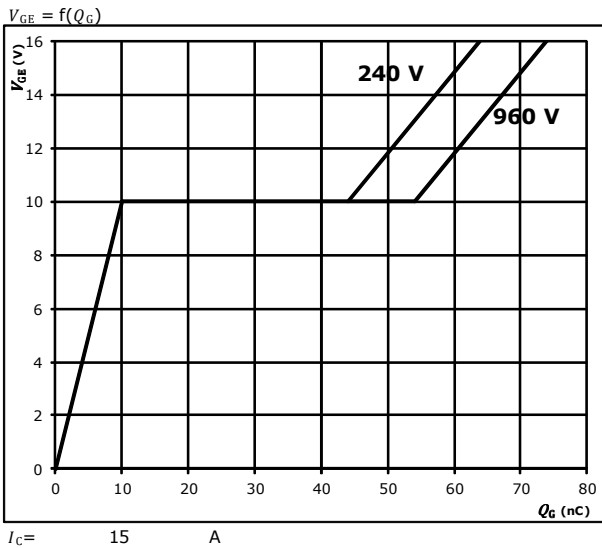


figure 6. IGBT

Safe operating area

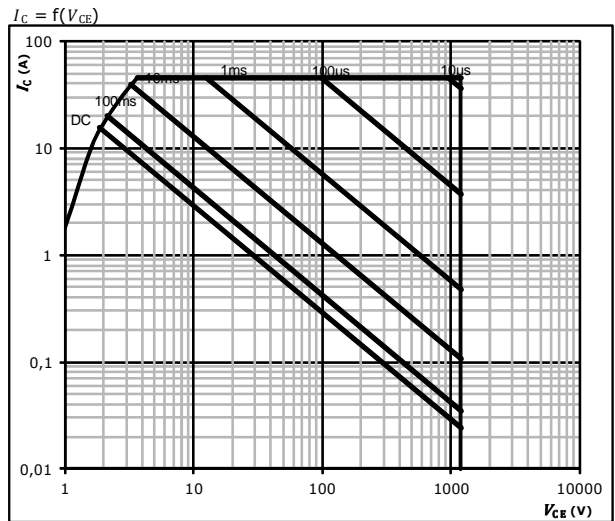


figure 7. IGBT

Short circuit duration as a function of V_{GE}

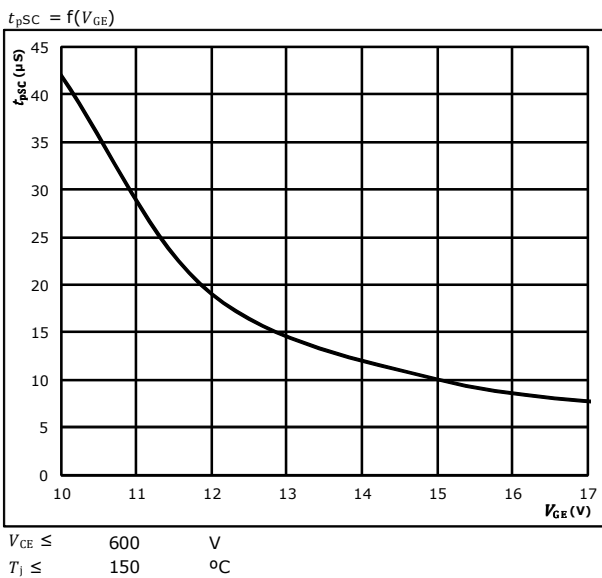
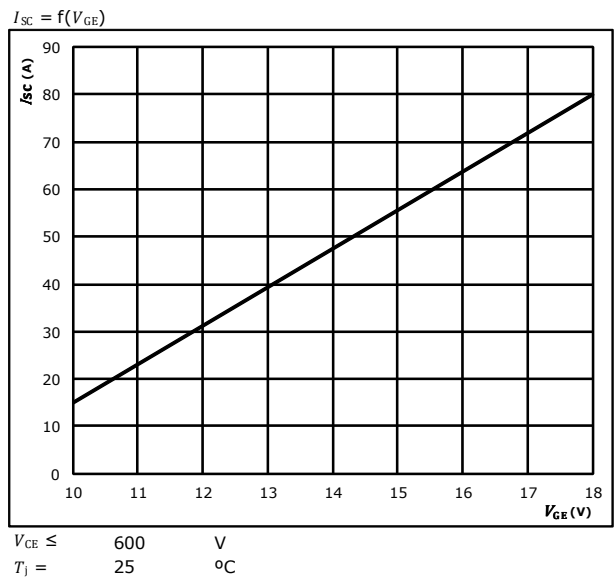


figure 8. IGBT

Typical short circuit current as a function of V_{GE}





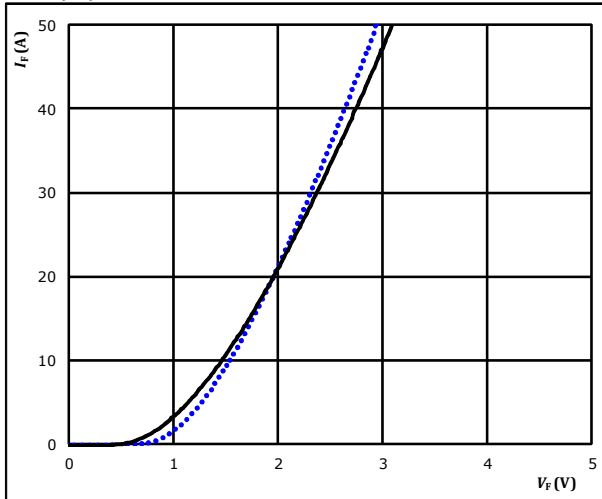
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Inverter Diode Characteristics

figure 1. FWD

Typical forward characteristics

$$I_F = f(V_F)$$

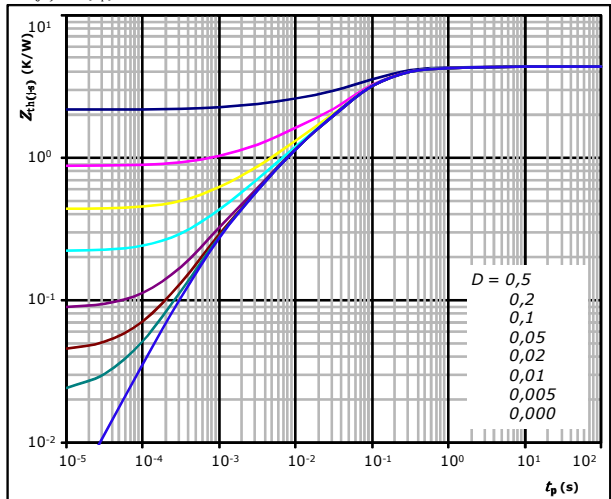


$t_p =$ 250 μ s T_j : 25 °C (dotted blue line), 125 °C (solid black line)

figure 2. FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D =$ t_p / T
 $R_{th(j-s)} =$ 4,37 K/W

FWD thermal model values

| R (K/W) | τ (s) |
|-----------|------------|
| 1,74E-01 | 2,44E+00 |
| 8,11E-01 | 2,19E-01 |
| 2,50E+00 | 6,24E-02 |
| 7,01E-01 | 6,51E-03 |
| 1,90E-01 | 8,68E-04 |



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20-1C12IBA015SH-LB18A08 datasheet

Brake Switch Characteristics

figure 1. IGBT

Typical transfer characteristics

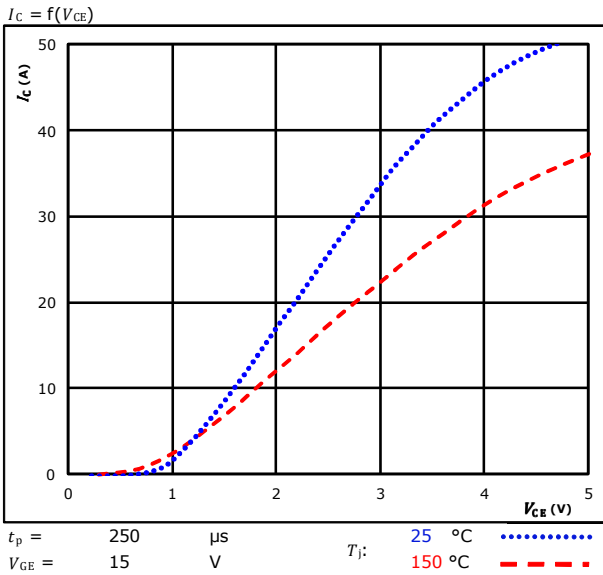


figure 2. IGBT

Typical output characteristics

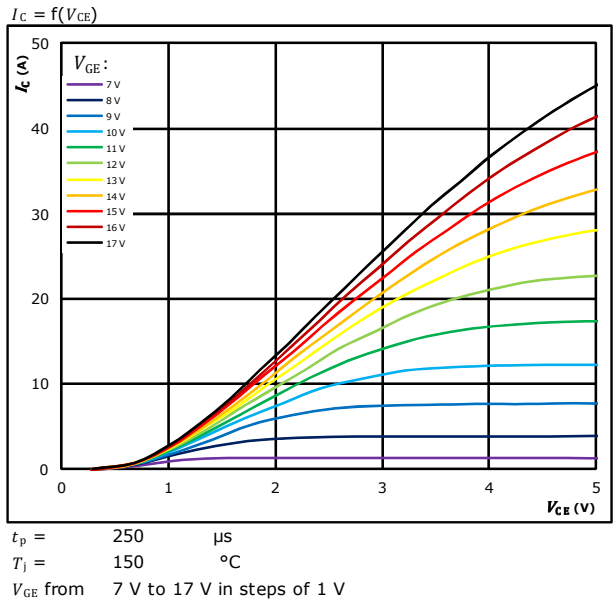


figure 3. IGBT

Typical transfer characteristics

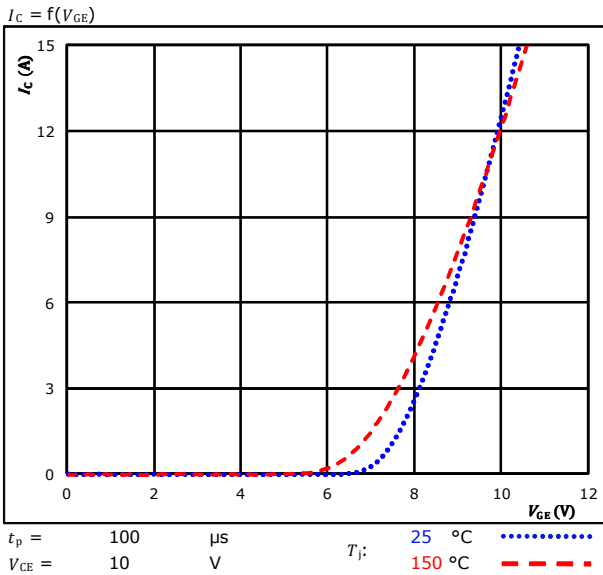
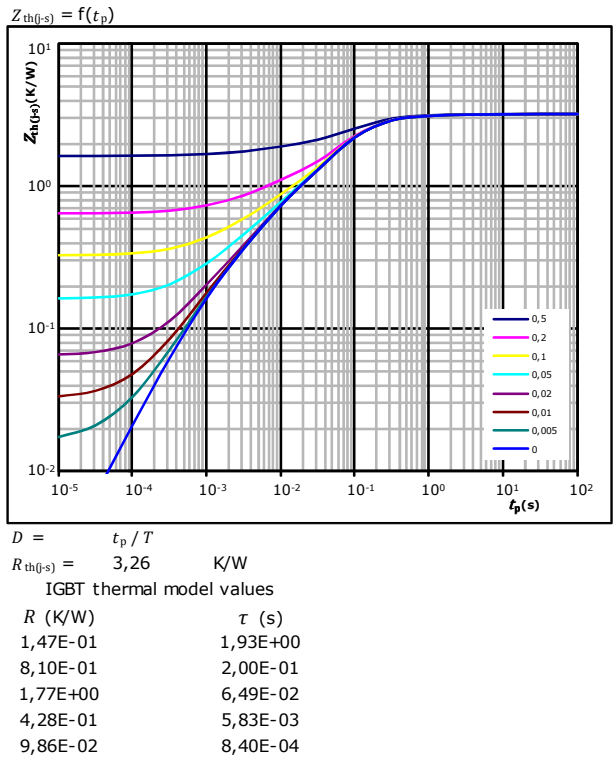


figure 4. IGBT

Transient thermal impedance as function of pulse duration





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Brake Switch Characteristics

figure 5. IGBT

Gate voltage vs gate charge

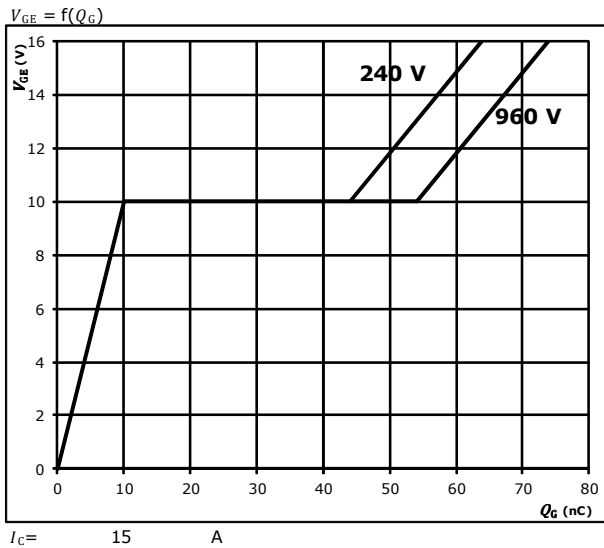


figure 6. IGBT

Safe operating area

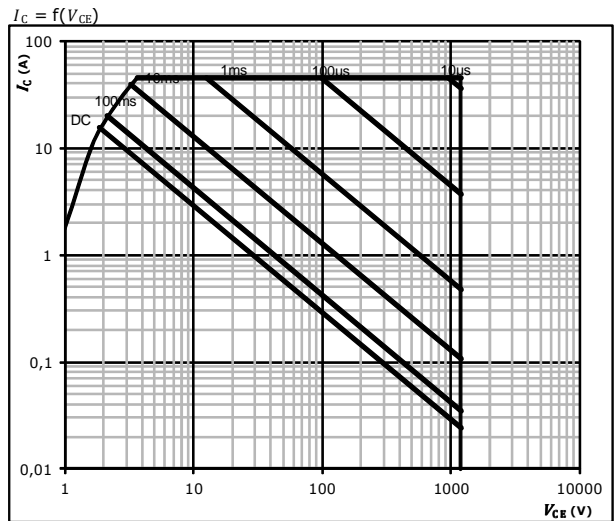


figure 7. IGBT

Short circuit duration as a function of V_{GE}

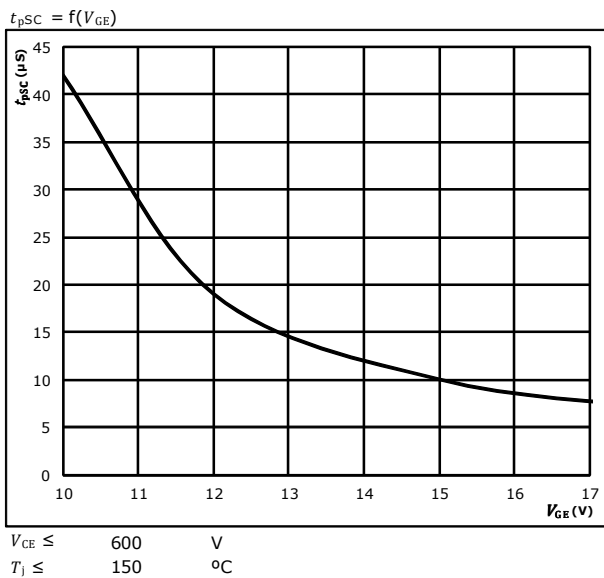
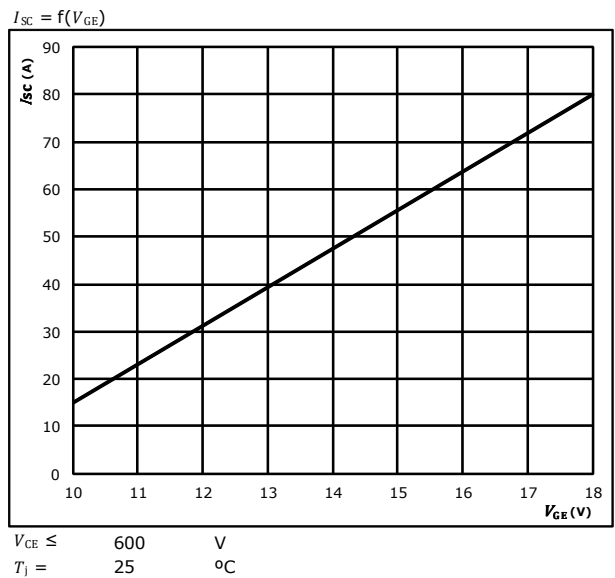


figure 8. IGBT

Typical short circuit current as a function of V_{GE}





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Brake Diode Characteristics

figure 1. FWD

Typical forward characteristics

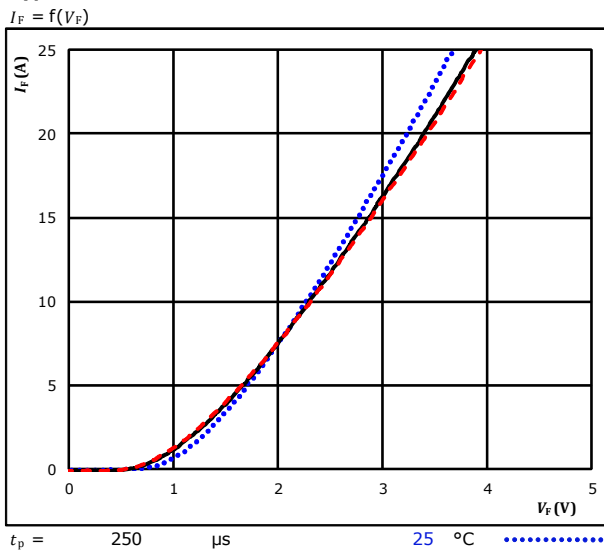
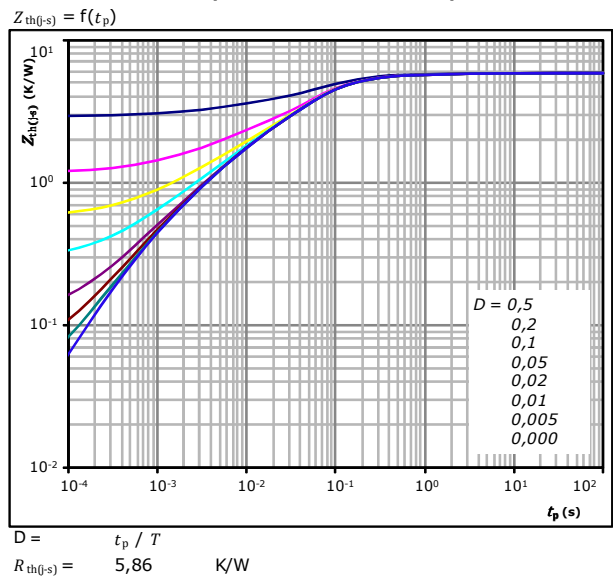


figure 2. FWD

Transient thermal impedance as a function of pulse width



FWD thermal model values

| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 8,94E-02 | 4,38E+00 |
| 3,15E-01 | 8,32E-01 |
| 2,01E+00 | 1,12E-01 |
| 2,33E+00 | 3,80E-02 |
| 9,08E-01 | 4,25E-03 |
| 2,13E-01 | 5,94E-04 |



Brake Sw. Protection Diode Characteristics

figure 1. FWD
Typical forward characteristics

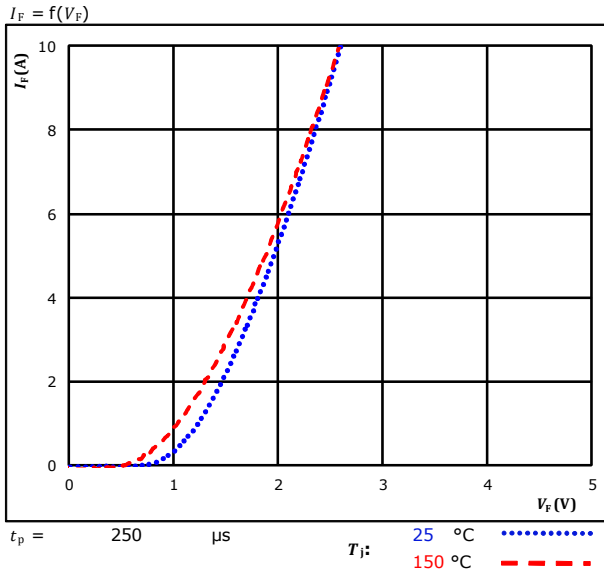
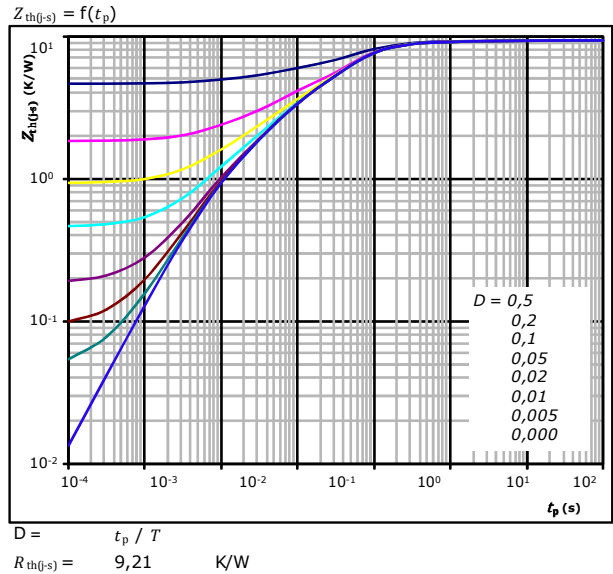


figure 2. FWD
Transient thermal impedance as a function of pulse width



FWD thermal model values

| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 2,80E-01 | 2,78E+00 |
| 1,47E+00 | 1,77E-01 |
| 4,89E+00 | 4,55E-02 |
| 1,92E+00 | 5,08E-03 |
| 6,42E-01 | 7,39E-04 |

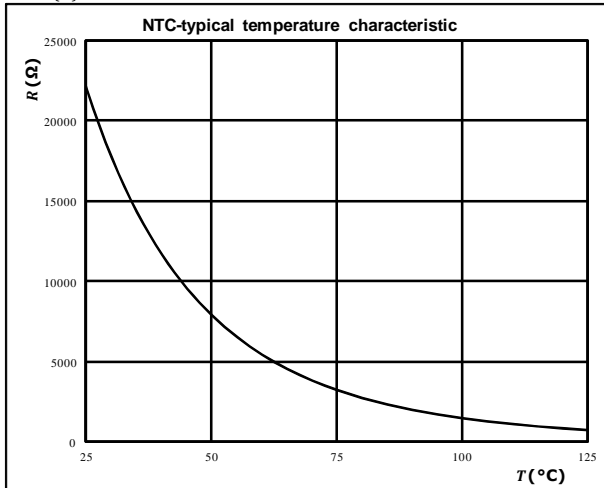


Thermistor Characteristics

figure 1. Thermistor

Typical NTC characteristic
as a function of temperature

$$R = f(T)$$



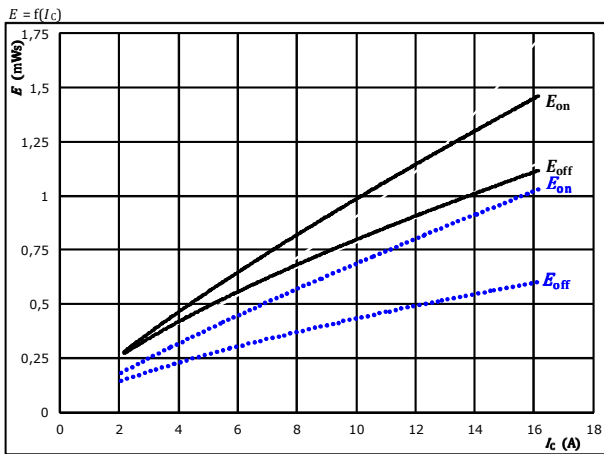


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Inverter Switching Characteristics

figure 1. IGBT

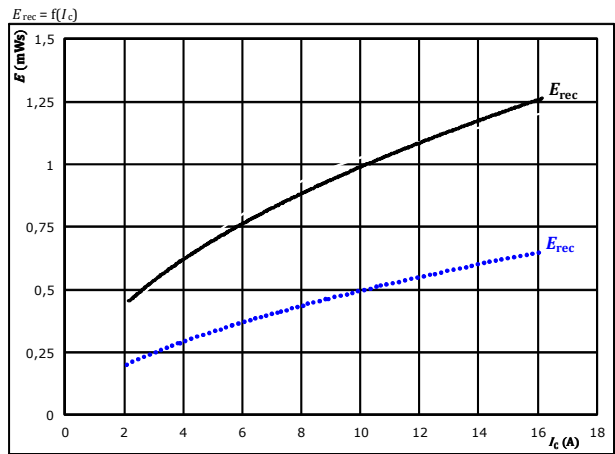
Typical switching energy losses as a function of collector current



With an inductive load at
 $V_{CE} = 600$ V
 $V_{CC} = 15$ V
 $V_{IN} = 5$ V
 $T_J = 125$ °C

figure 2. FWD

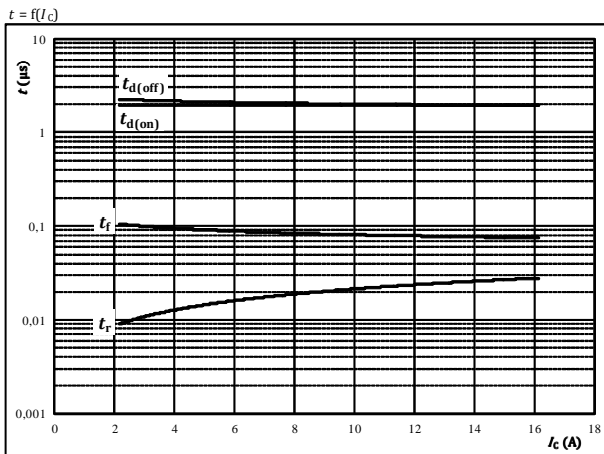
Typical reverse recovered energy loss as a function of collector current



With an inductive load at
 $V_{CE} = 600$ V
 $V_{CC} = 15$ V
 $V_{IN} = 5$ V
 $T_J = 125$ °C

figure 3. IGBT

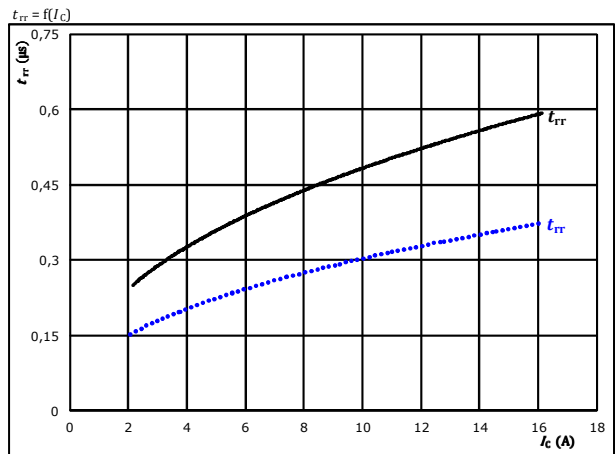
Typical switching times as a function of collector current



With an inductive load at
 $T_J = 125$ °C
 $V_{CE} = 600$ V
 $V_{CC} = 15$ V
 $V_{IN} = 5$ V

figure 4. FWD

Typical reverse recovery time as a function of collector current



At
 $V_{CE} = 600$ V
 $V_{CC} = 15$ V
 $V_{IN} = 5$ V
 $T_J = 125$ °C



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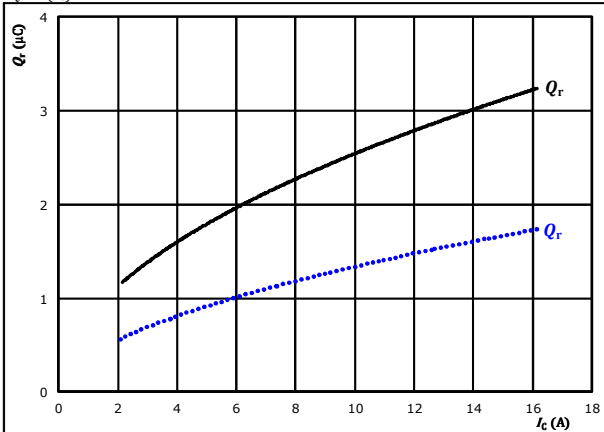
20-1C12IBA015SH-LB18A08 datasheet

Inverter Switching Characteristics

figure 5. FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_C)$$

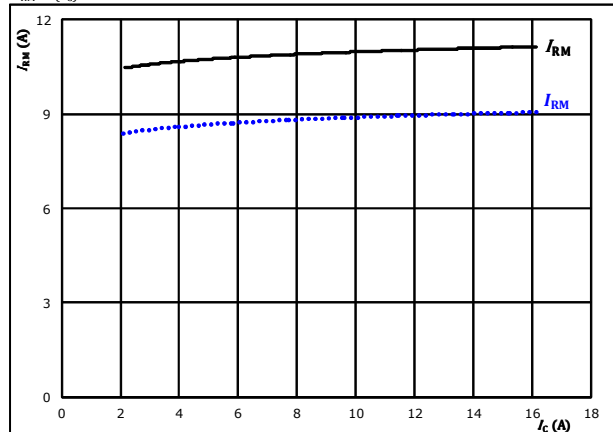


At $V_{CE} = 600$ V
 $V_{CC} = 15$ V
 $V_{IN} = 5$ V
 $T_j = 25$ °C (dotted blue line)
 $T_j = 125$ °C (solid black line)

figure 6. FWD

Typical peak reverse recovery current current as a function of collector current

$$I_{RM} = f(I_C)$$

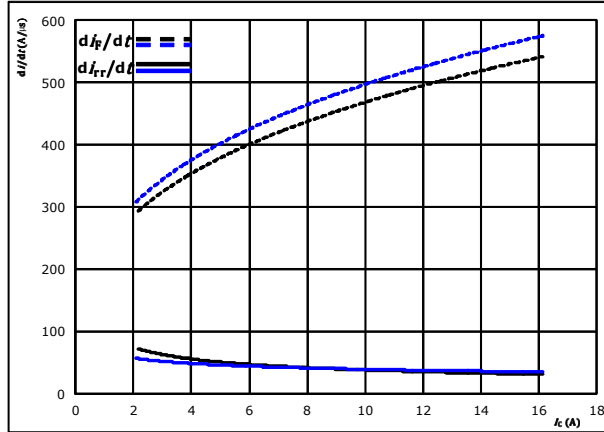


At $V_{CE} = 600$ V
 $V_{CC} = 15$ V
 $V_{IN} = 5$ V
 $T_j = 25$ °C (dotted blue line)
 $T_j = 125$ °C (solid black line)

figure 7. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

$$di_F/dt, di_{rr}/dt = f(I_C)$$

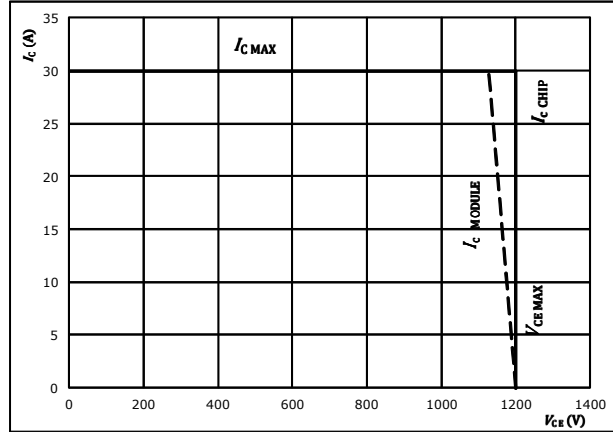


At $V_{CE} = 600$ V
 $V_{CC} = 15$ V
 $V_{IN} = 5$ V
 $T_j = 25$ °C (dotted blue line)
 $T_j = 125$ °C (solid black line)

figure 8. IGBT

Reverse bias safe operating area

$$I_C = f(V_{CE})$$



At $T_j = 175$ °C



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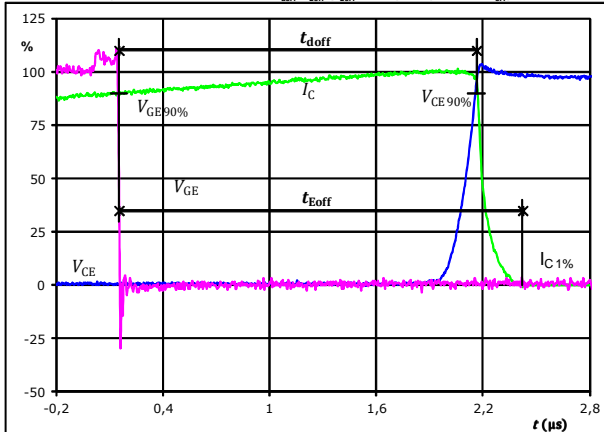
Inverter Switching Definitions

General conditions

| | | |
|------------|---|--------------|
| T_j | = | 125 °C |
| R_{gon} | = | 0,5 Ω |
| R_{goff} | = | 0,5 Ω |

figure 1. IGBT

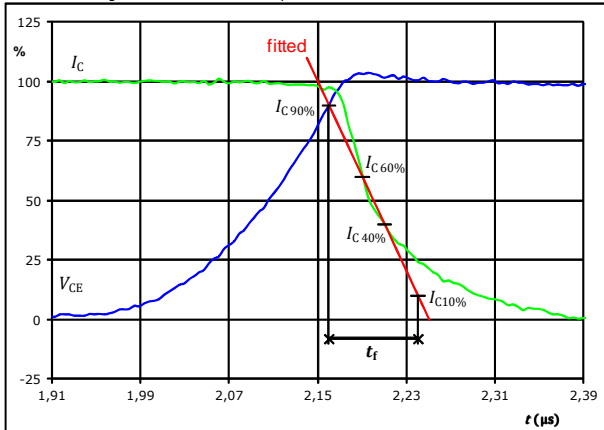
Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})



| | | |
|-------------------|-------|---------|
| $V_{GE}(0\%) =$ | 0 | V |
| $V_{GE}(100\%) =$ | 5 | V |
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 9 | A |
| $t_{doff} =$ | 2,012 | μs |
| $t_{Eoff} =$ | 2,271 | μs |

figure 3. IGBT

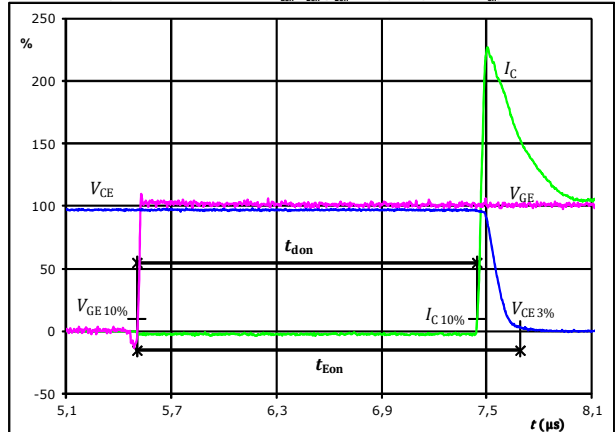
Turn-off Switching Waveforms & definition of t_f



| | | |
|----------------|-------|---------|
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 9 | A |
| $t_f =$ | 0,088 | μs |

figure 2. IGBT

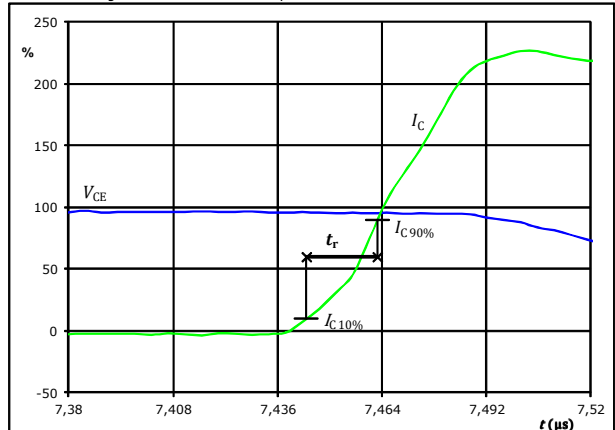
Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})



| | | |
|-------------------|-------|---------|
| $V_{GE}(0\%) =$ | 0 | V |
| $V_{GE}(100\%) =$ | 5 | V |
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 9 | A |
| $t_{don} =$ | 1,938 | μs |
| $t_{Eon} =$ | 2,187 | μs |

figure 4. IGBT

Turn-on Switching Waveforms & definition of t_r



| | | |
|----------------|-------|---------|
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 9 | A |
| $t_r =$ | 0,019 | μs |

* t_{don} , t_{doff} include gate driver propagation delay



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Inverter Switching Characteristics

figure 5. IGBT

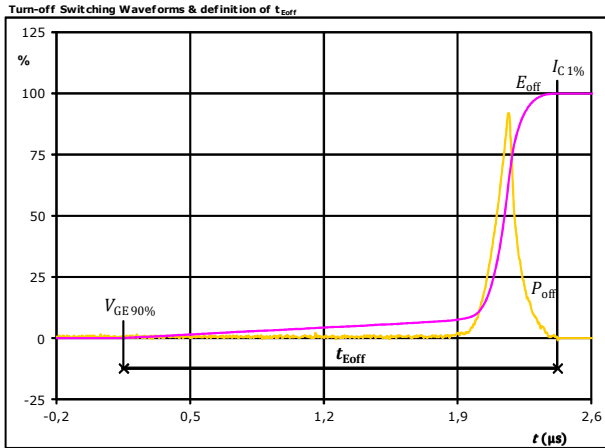


figure 6. IGBT

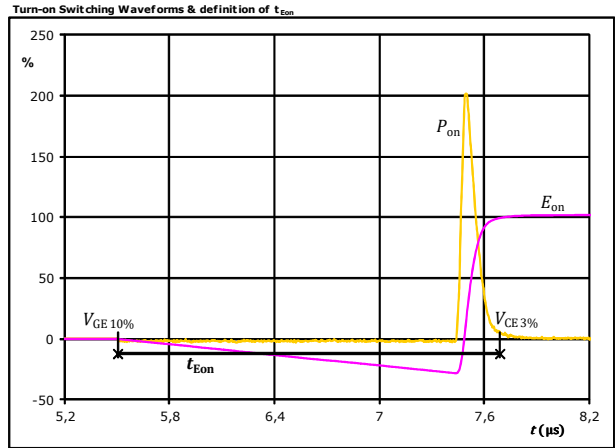
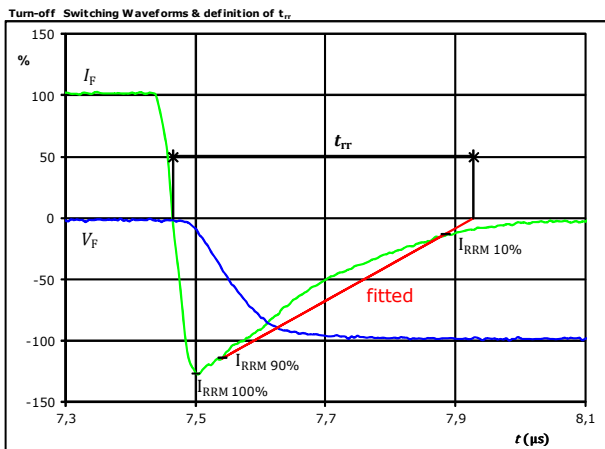


figure 7. FWD





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Inverter Switching Characteristics

figure 8. FWD

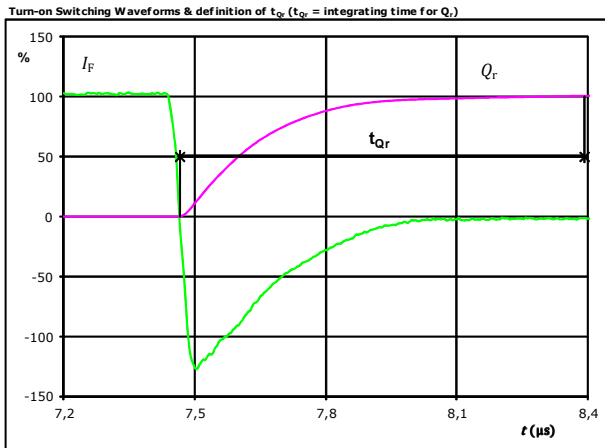
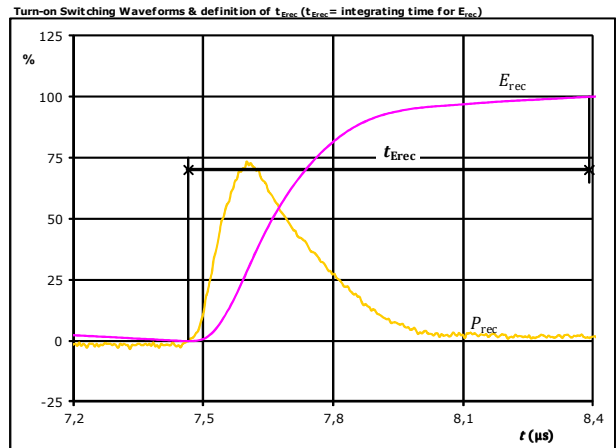


figure 9. FWD





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Brake Switching Characteristics

figure 1. IGBT

Typical switching energy losses as a function of collector current

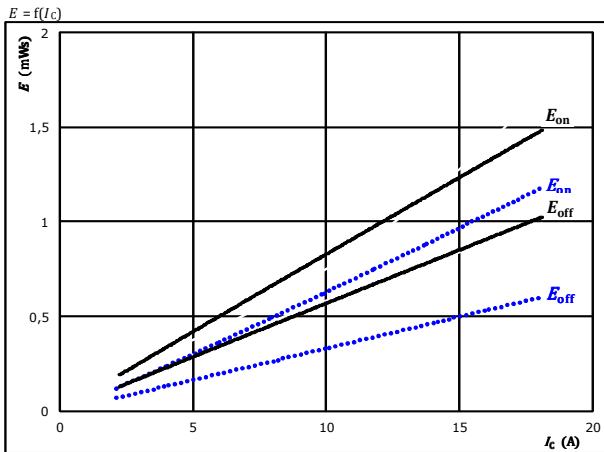


figure 2. FWD

Typical reverse recovered energy loss as a function of collector current

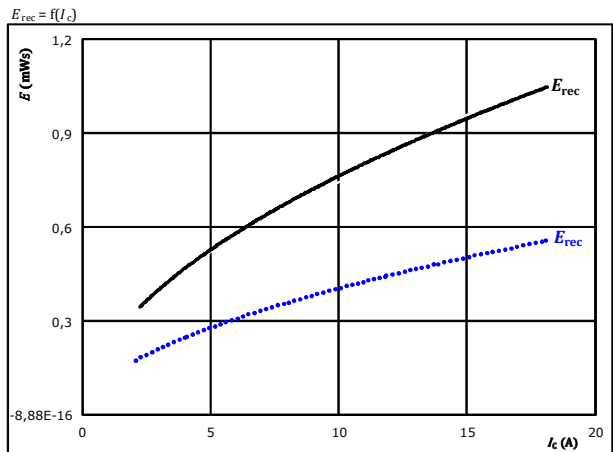


figure 3. IGBT

Typical switching times as a function of collector current

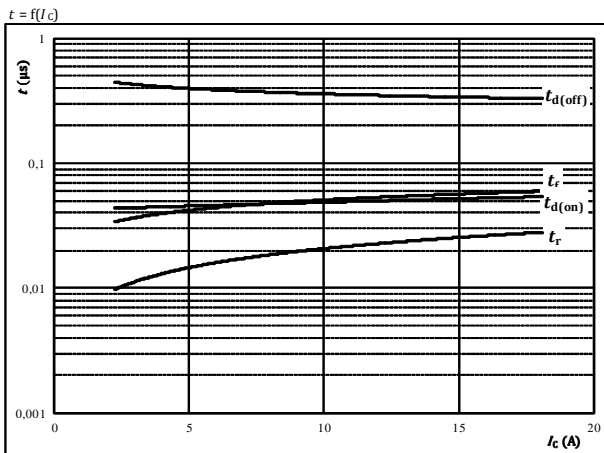
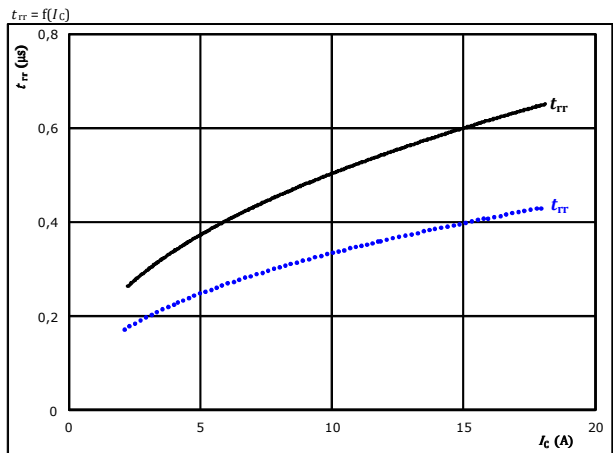


figure 4. FWD

Typical reverse recovery time as a function of collector current





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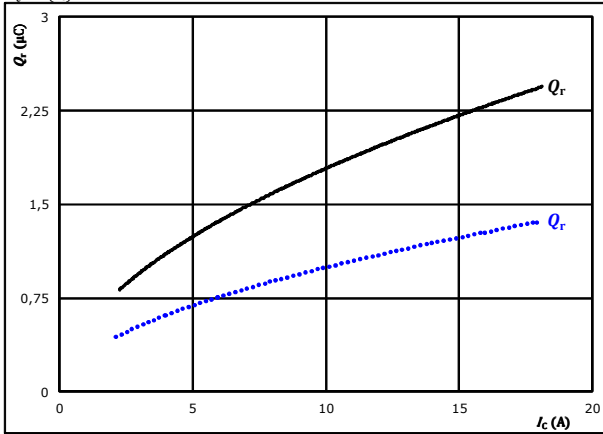
20-1C12IBA015SH-LB18A08 datasheet

Brake Switching Characteristics

figure 5. FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_C)$$

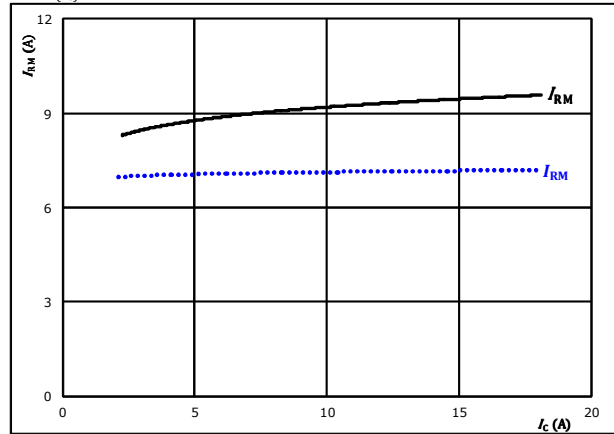


At $V_{CE} = 600$ V
 $V_{IN} = 5$ V
 $V_{CC} = 15,0$ V
 $T_j = 25$ °C (dotted blue line)
 $T_j = 125$ °C (solid black line)

figure 6. FWD

Typical peak reverse recovery current current as a function of collector current

$$I_{RM} = f(I_C)$$

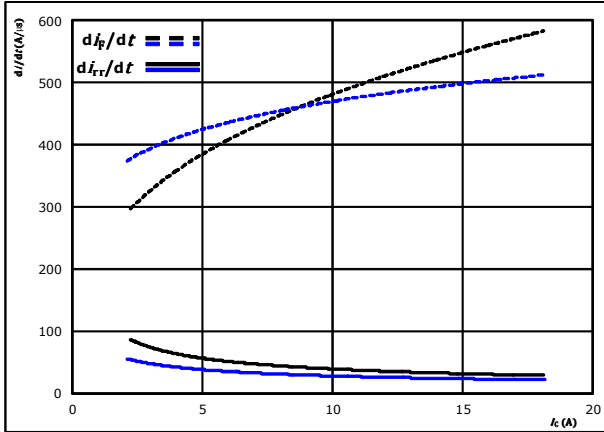


At $V_{CE} = 600$ V
 $V_{IN} = 5$ V
 $V_{CC} = 15,0$ V
 $T_j = 25$ °C (dotted blue line)
 $T_j = 125$ °C (solid black line)

figure 7. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

$$di_f/dt, di_{rr}/dt = f(I_C)$$

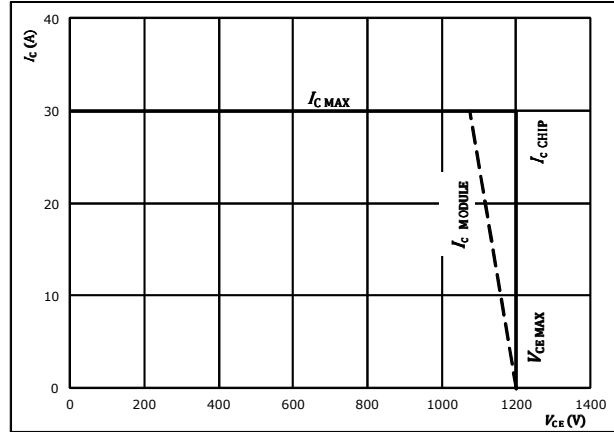


At $V_{CE} = 600$ V
 $V_{IN} = 5$ V
 $V_{CC} = 15,0$ V
 $T_j = 25$ °C (dotted blue line)
 $T_j = 125$ °C (solid black line)

figure 8. IGBT

Reverse bias safe operating area

$$I_C = f(V_{CE})$$



At $T_j = 175$ °C



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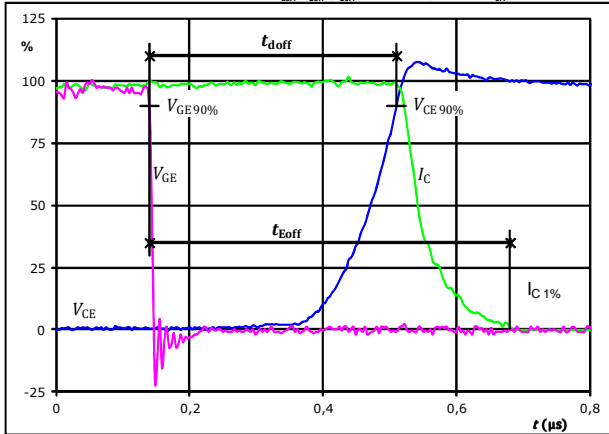
Brake Switching Definitions

General conditions

| | | |
|----------|---|--------|
| T_j | = | 125 °C |
| V_{CC} | = | 15 V |

figure 1. IGBT

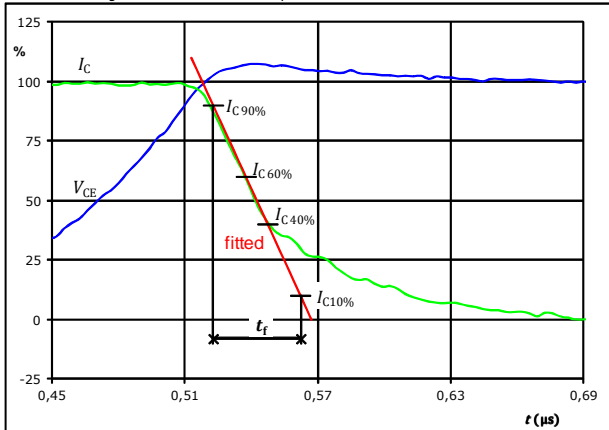
Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})



| | | |
|-------------------|-------|----|
| $V_{IN}(0\%) =$ | 0 | V |
| $V_{IN}(100\%) =$ | 5 | V |
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 10 | A |
| $t_{doff} =$ | 0,369 | μs |
| $t_{Eoff} =$ | 0,541 | μs |

figure 3. IGBT

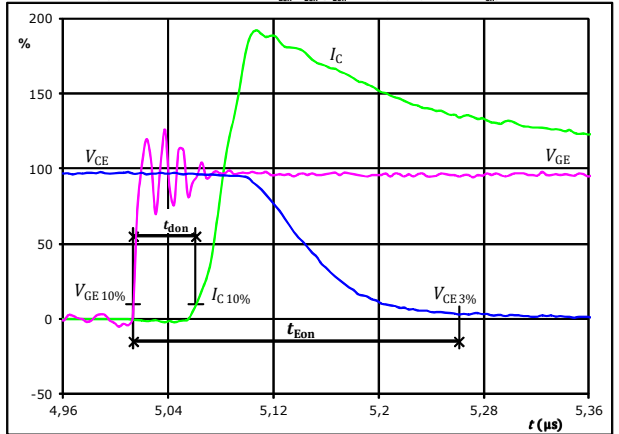
Turn-off Switching Waveforms & definition of t_r



| | | |
|----------------|-------|----|
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 10 | A |
| $t_r =$ | 0,043 | μs |

figure 2. IGBT

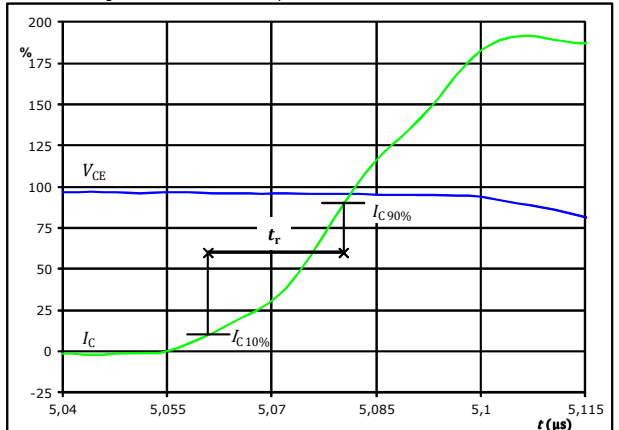
Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})



| | | |
|-------------------|-------|----|
| $V_{IN}(0\%) =$ | 0 | V |
| $V_{IN}(100\%) =$ | 5 | V |
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 10 | A |
| $t_{don} =$ | 0,049 | μs |
| $t_{Eon} =$ | 0,248 | μs |

figure 4. IGBT

Turn-on Switching Waveforms & definition of t_r



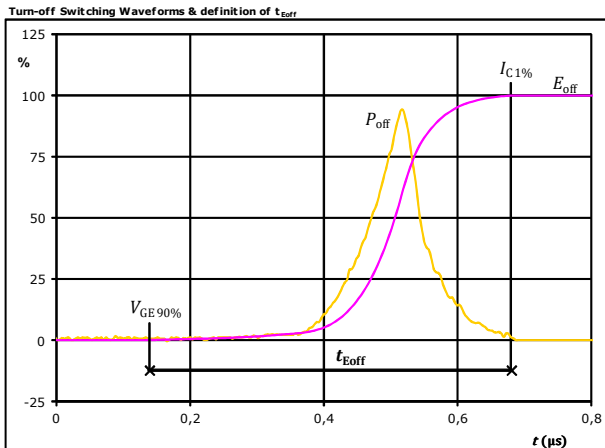
| | | |
|----------------|-------|----|
| $V_C(100\%) =$ | 600 | V |
| $I_C(100\%) =$ | 10 | A |
| $t_r =$ | 0,020 | μs |



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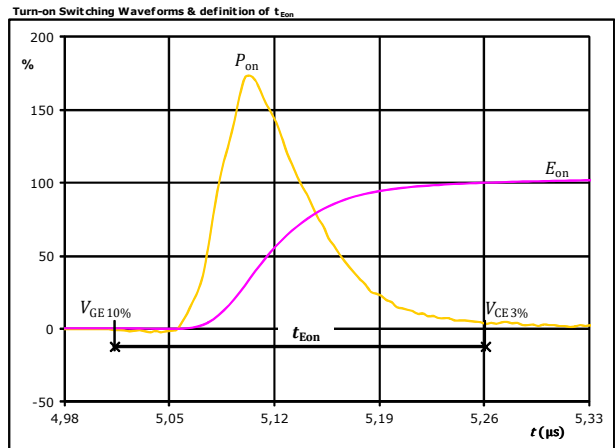
Brake Switching Characteristics

figure 5. IGBT



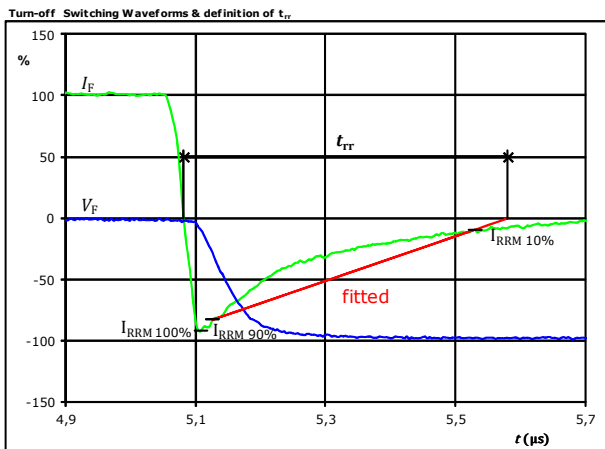
$P_{\text{off}}(100\%) = 6,15$ kW
 $E_{\text{off}}(100\%) = 0,60$ mJ
 $t_{\text{Eoff}} = 0,54$ μs

figure 6. IGBT



$P_{\text{on}}(100\%) = 6,15$ kW
 $E_{\text{on}}(100\%) = 0,77$ mJ
 $t_{\text{Eon}} = 0,25$ μs

figure 7. FWD



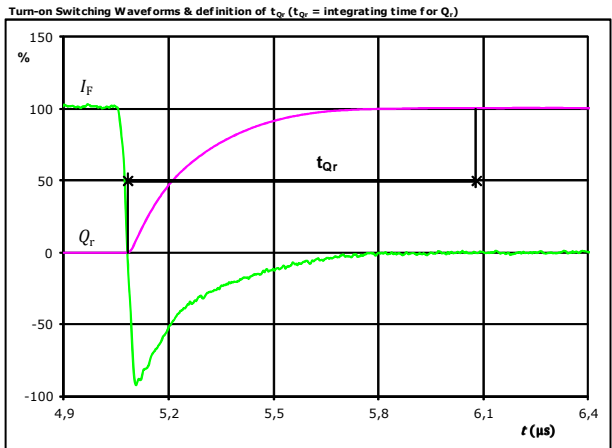
$V_{\text{F}}(100\%) = 600$ V
 $I_{\text{F}}(100\%) = 10$ A
 $I_{\text{RRM}}(100\%) = -9$ A
 $t_{\text{rr}} = 0,494$ μs



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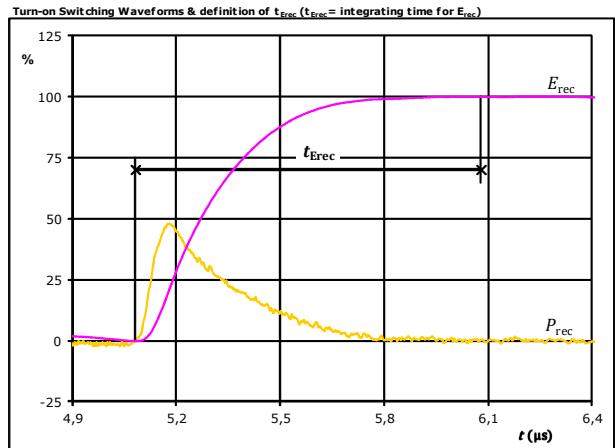
Brake Switching Characteristics

figure 8. FWD



I_F (100%) = 10 A
 Q_r (100%) = 1,76 μC
 t_{Qr} = 1,00 μs

figure 9. FWD





P_{rec} (100%) = 6,15 kW
 E_{rec} (100%) = 0,75 mJ
 t_{Erec} = 1,00 μs



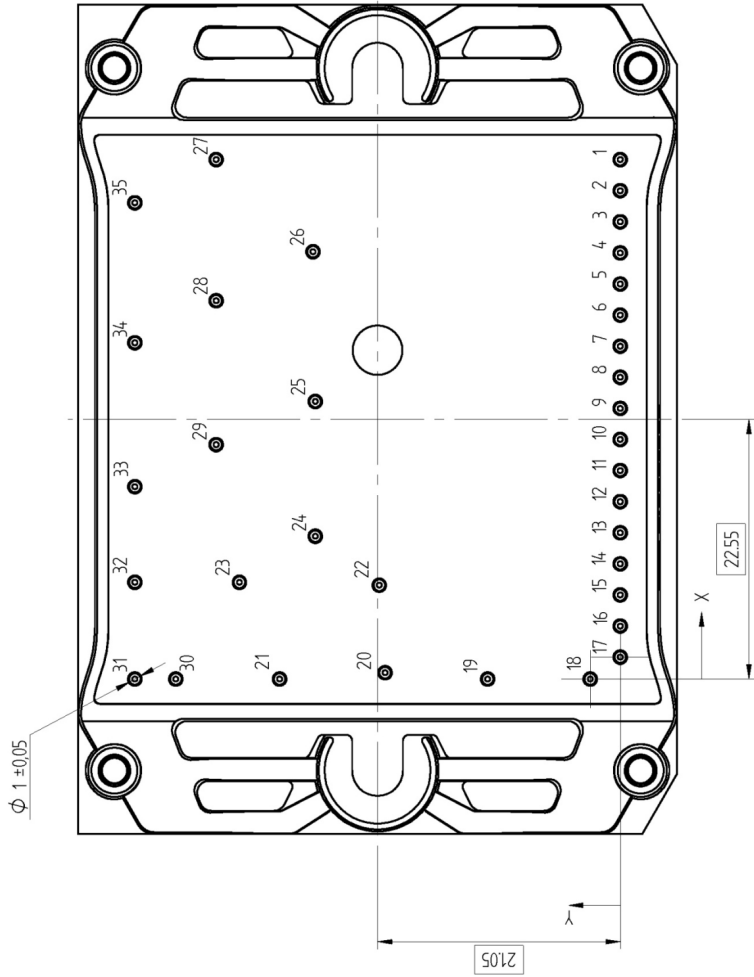
20-1C12IBA015SH-LB18A08

datasheet

Vincotech

| Ordering Code & Marking | | | | | | | |
|---|------------|----------------------------|-------------------------|-----------|-----------|-------|--------|
| Version | | | Ordering Code | | | | |
| without thermal paste 12 mm housing with solder pins | | | 20-1C12IBA015SH-LB18A08 | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| <div><div>NN-NNNNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLLL SSSS</div><div></div><div></div></div> | Text | Name | | Date code | UL & VIN | Lot | Serial |
| | | NN-NNNNNNNNNNNNNN-TTTTTTVV | | WWYY | UL VIN | LLLLL | SSSS |
| | Datamatrix | Type&Ver | Lot number | Serial | Date code | | |
| | | TTTTTTTVV | LLLLL | SSSS | WWYY | | |

| Pin table | | | | Outline | | | |
|-----------|-------|-------|----------|---------|--|--|--|
| Pin | X | Y | Function | | | | |
| 1 | 45,1 | 0 | WH | | | | |
| 2 | 42,4 | 0 | WL | | | | |
| 3 | 39,7 | 0 | RW+ | | | | |
| 4 | 37 | 0 | RW- | | | | |
| 5 | 34,3 | 0 | GND | | | | |
| 6 | 31,6 | 0 | VCC | | | | |
| 7 | 28,9 | 0 | VH | | | | |
| 8 | 26,2 | 0 | VL | | | | |
| 9 | 23,5 | 0 | RV+ | | | | |
| 10 | 20,8 | 0 | RV- | | | | |
| 11 | 18,1 | 0 | UH | | | | |
| 12 | 15,4 | 0 | UL | | | | |
| 13 | 12,7 | 0 | RU+ | | | | |
| 14 | 10 | 0 | RU- | | | | |
| 15 | 7,3 | 0 | RST | | | | |
| 16 | 4,6 | 0 | FO | | | | |
| 17 | 1,9 | 0 | NTC | | | | |
| 18 | 0 | 2,6 | BRCG | | | | |
| 19 | 0 | 11,5 | L3 | | | | |
| 20 | 0,55 | 20,4 | L2 | | | | |
| 21 | 0 | 29,55 | L1 | | | | |
| 22 | 8,15 | 20,9 | DC1- | | | | |
| 23 | 8,4 | 33,03 | BRE | | | | |
| 24 | 12,4 | 26,45 | EU | | | | |
| 25 | 24,1 | 26,45 | EV | | | | |
| 26 | 37,1 | 26,65 | EW | | | | |
| 27 | 45,1 | 35,05 | DC2+ | | | | |
| 28 | 32,85 | 35,05 | DC2+ | | | | |
| 29 | 20,35 | 35,05 | DC2+ | | | | |
| 30 | 0 | 38,55 | DC1+ | | | | |
| 31 | 0 | 42,1 | BRC+ | | | | |
| 32 | 8,4 | 42,1 | BRC | | | | |
| 33 | 16,7 | 42,1 | U | | | | |
| 34 | 29,2 | 42,1 | V | | | | |
| 35 | 41,35 | 42,1 | W | | | | |



Tolerance of pinpositions: ±0.5mm at the end of pins
Dimension of coordinate axis is only offset without tolerance

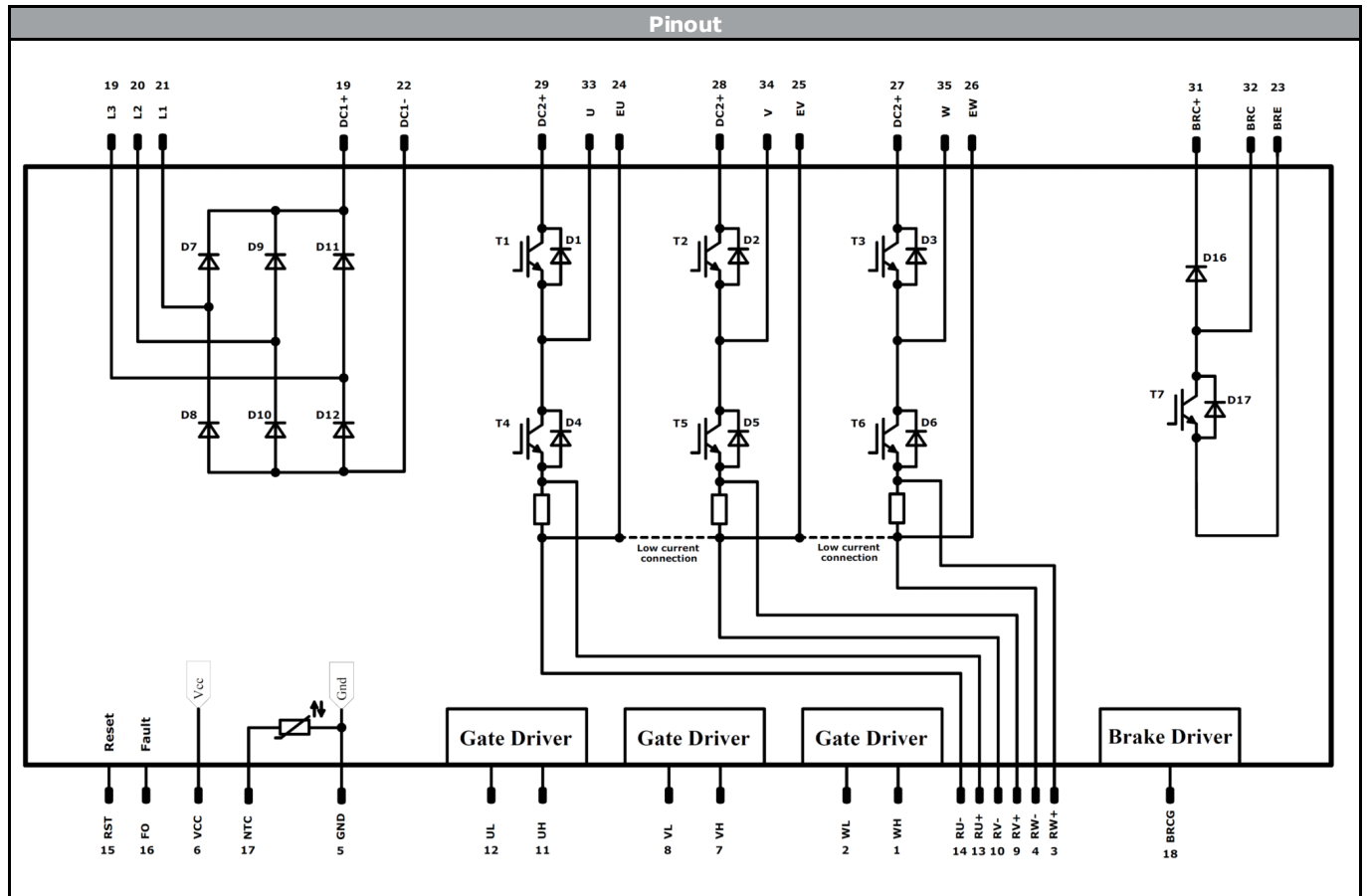


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| Pin Descriptions | | | | | | |
|------------------|----------|---|------------------------|----------|----------------------|--|
| Pin | Function | Description | Power pin descriptions | | | |
| 1 | WH | Signal input for high-side W phase | Pin | Function | Description | |
| 2 | WL | Signal input for low-side W phase | 19 | L3 | Rectifier input L3 | |
| 3 | RW+ | W phase shunt + | 20 | L2 | Rectifier input L2 | |
| 4 | RW- | W phase shunt - | 21 | L1 | Rectifier input L1 | |
| 5 | GND | Signal ground | 22 | DC1- | Rectifier output DC- | |
| 6 | VCC | Driver circuit supply voltage | 23 | BRE | Brake Open emitter | |
| 7 | VH | Signal input for high-side V phase | 24 | EU | Open emitter U phase | |
| 8 | VL | Signal input for low-side V phase | 25 | EV | Open emitter V phase | |
| 9 | RV+ | V phase shunt + | 26 | EW | Open emitter W phase | |
| 10 | RV- | V phase shunt - | 27 | DC2+ | Inverter input DC+ | |
| 11 | UH | Signal input for high-side U phase | 28 | DC2+ | Inverter input DC+ | |
| 12 | UL | Signal input for low-side U phase | 29 | DC2+ | Inverter input DC+ | |
| 13 | RU+ | U phase shunt + | 30 | DC1+ | Rectifier output DC+ | |
| 14 | RU- | U phase shunt - | 31 | BRC+ | Brake input DC+ | |
| 15 | RST | Fault latch reset (min. 500ns pulse) | 32 | BRC | Brake output | |
| 16 | FO | Fault latch input/output (negative logic, open drain) | 33 | U | Output U phase | |
| 17 | NTC | Temperature sensor connector | 34 | V | Output V phase | |
| 18 | BRCG | Signal input for Brake gate drive | 35 | W | Output W phase | |



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| Identification | | | | | |
|---------------------------|-----------|---------|---------|----------------------------|---------|
| ID | Component | Voltage | Current | Function | Comment |
| D8, D7, D10, D9, D12, D11 | Rectifier | 1600 V | 30 A | Rectifier Diode | |
| T4, T1, T5, T2, T6, T3 | IGBT | 1200 V | 15 A | Inverter Switch | |
| D1, D4, D2, D5, D3, D6 | FWD | 1200 V | 15 A | Inverter Diode | |
| R1, R2, R3 | Resistor | | 9 A | Inverter Shunt | |
| T7 | IGBT | 1200 V | 15 A | Brake Switch | |
| D16 | FWD | 1200 V | 7,5 A | Brake Diode | |
| D17 | FWD | 1200 V | 3 A | Brake Sw. Protection Diode | |



| Packaging instruction | | | |
|--------------------------------------|------|----------|-------------|
| Standard packaging quantity (SPQ) 90 | >SPQ | Standard | <SPQ Sample |

| Handling instruction |
|--|
| Handling instructions for <i>flow</i> 1C packages see vincotech.com website. |

| Package data |
|---|
| Package data for <i>flow</i> 1C packages see vincotech.com website. |

| UL recognition and file number |
|---|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.  |

| Document No.: | Date: | Modification: | Pages |
|-------------------------------|--------------|---------------|-------|
| 20-1C12IBA015SH-LB18A08-D1-14 | 25 Aug. 2017 | | |

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